#### **Features**

Stability: ±1.5 ppm over - 20°C to +70°C 100 MHz: Sine wave: 3 dBm min

Phase Noise:

-135dBc/Hz or better at 1KHz -145dBc/Hz or better at 10KHz 13.2 mm x 20.8 mm x 10.0 mm Hermetically Sealed Package

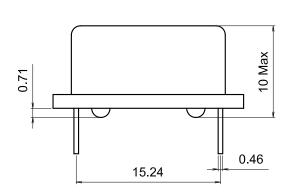
### **Typical Applications**

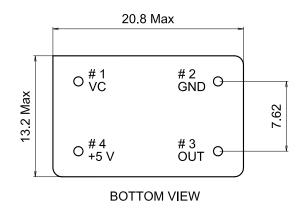
Synthesizer Reference Test Instruments Microwave Communications LO Weather Radar

## **Description**

The GSTX1217-100MHz-A device offers excellent frequency stability and low phase noise performance based on analog compensation techniques and suitable for harsh environments in a hermetically sealed package.

### **Mechanical Drawing and PIN Function**





13.2 x 20.8 x 10.0 mm

# **Specifications**

#	TCXO Specification		Sym.	Condition	Value			Unit	Included in the
					Min.	Тур.	Max.		test data
1.1	Nominal Frequency		Fo			00.000000		MHz	
1.2				+25 C +/- 5 C	-250.0		+250.0	ppb	Vc : 2.5V
	RF output		1		1	~.		_	T
2.1	Wave form				Sine wave				
2.2	Output Power				3.0			dBm	
2.3	Harmonics			Sub harmonics -45 dBc			-25	dBc	harmonics
2.4	Load					50		Ohms	
	Frequency conti	rol							
3.1									
3.2	Control voltage	range	$V_c$		0.0	2.5	5.0	V	
3.3								1	
3.4	Slope				/ 4 ~ ~	Positive		DDI 4	
3.5	Pull range				+/- 10.0		<u> </u>	PPM	
2.6	run range			<u> </u>				1	
3.6							-	1	
								-	
	Power supply								
4.1	Voltage		Vcc	1	4.75	5	5.25	V	
4.2	Voltage		7 00		4.73		3.23	•	
4.3	DC Current						30	mA	
	De current								
	Frequency stabi		1		4.500			nnm	
5.1	vs. temperature			From -20 C to +70 C	-1.500		+1.500	ppm	
5.2		1		Includes voltage and load variation					
6	Aging	per year		after 30 days of operation at time of shipment			+/- 1.0	ppm	
				at 1 Hz offset					
	SSB Phase Noise			at 10 Hz offset				dBc/Hz	
7.1				at 100 Hz offset			-115		
,,,			at 1 kHz offset			-135	abo, iii		
				at 10 kHz offset			-145	1	
7.2							-173		
1.4			1			<u> </u>	<u> </u>	1	
Maxii	num ratings, env	ironmental. m	echanical c	onditions.					
		<b></b>							
Operating temperature range -20 C to									
			-55 C to						